X-ray Photoemission Measurements and Electronic Structure of HgBa₂CaCu₂O_{6+δ}

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Abstract

HgBa₂CaCu₂O_{6+δ} (Hg- 1212.) thin films grown epitaxially on SrTiO₃ (100) substrates have been chemically etched and studied with x-ray photoelectron spectroscopy (XPS). The XPS data presented here are the first on an epitaxial thin film of a mercury cuprate superconductor, the first in which signals from the superconducting phase dominate all the core level spectra, and the first to exhibit a clear Fermi edge in the valence band region. Hg is found to be in a single chemical state, contrary to previous reports based on measurements from sintered polycrystalline pellets. The Ba, Ca, Cu, and O core levels are similar to those measured from Tl₂Ba₂CaCu₂O_{8+δ} ('N-2212), which is chemically and structurally most similar to Hg-1 212, and other cuprate superconductors. Despite the similarities in the core level spectra, distinct differences are observed in the valence bands of Hg-1212 and TI-2212 which are attributed to differences in the apical oxygen densities of states.

Interest in Hg cuprate high temperature superconductors (HTS), HgBa₂Ca_{1-n}Cu_nO_{2n+2+8} (Hg-1201, Hg-1212, and Hg-1223 for n=1, 2, 3, respectively), has been stimulated by observations of higher superconducting transition temperatures, T_c , than are observed for other cuprates ($T_c \sim 95$ K for Hg- 1201, T_c - 125 K for Hg- 1212, and T_c - 135 K for Hg- 1223 at ambient pressure). ^{1,2} It has also been found that T_c can be increased to over 150 K when these materials are placed under quasi-hydrostatic pressure. ³ In addition, the recent growth of high quality Hg- 1212 epitaxial thin films⁴ and the fabrication of these films into superconducting quantum interference devices (SQUIDs)⁵ which operate at temperatures in excess of 110 K demonstrates the potential technological importance of these materials.

X-ray photoelectron spectroscopy (XPS) has been utilized to characterize the chemical states of the component elements and the valence band densities of states in numerous studies of HTS materials.6 Among the results of previous studies of HTS materials are a set of well-defined spectral features which are characteristic of high quality surfaces: 7,8 a high binding energy Cu+2 satellite in the Cu 2p core level region, low binding energy O 1s (528 -529 eV) and alkaline earth core level signals with little or no intensity at higher binding energies, and a clear Fermi edge in the valence band region. These studies on HTS materials which are chemically and structurally similar to the Hg cuprates should provide valid guidelines for judging the quality of the XPS XPS measurements on Hg-1212 and Hg-12239 and on Hg- 120110 have measurements. previously been reported. In one study only Cu 2p and Hg 4f core level measurements were presented, 10 so that it is not possible to assess the surface cleanliness. In the other study, 9 a complete set of core level measurements was presented. Spatially variant chemical inhomogeneities and differential sample charging were reported, and the spectra included prominent, or even dominant, signals which were attributed to nonsuperconducting grain boundary species. Both of these previous studies^{9,10} mentioned valence band measurements, including a report of a weak Fermi edge, 10 which were not presented. Higher quality XPS data for Hg cuprates are clearly desirable.

In this work, XPS measurements are reported for a Hg-1212 epitaxial thin film, for which signals from grain boundary species are not expected to be as severe a problem as it is for sintered powders. Core level measurements are presented which are dominated by signals attributable to the superconducting phase, and are compared to those measured from Tl₂Ba₂CaCu₂O₈₊₈ (Tl-2212), which is chemically and structurally most similar to Hg-1212. Measurements of the valence band of Hg-1212 which exhibit a clear Fermi edge are presented for the first time, and are compared to the measured valence band of Tl-2212 and to the densities of states reported in Hg-1212 and Tl-2212 band structure calculations. 12,13

The Hg-1212 films are grown epitaxially on SrTiO₃ (100) substrates by laser ablation, Details of the film growth and characterization are described elsewhere.⁴ The film used for this study was one of a batch of four grown together, of which the other three all exhibited zero resistance at 120 K, and was ampouled for transport to the XPS spectrometer. The ampoule was broken in the inert ultrahigh purity nitrogen atmosphere of a dry box which encloses the XPS load lock area. The surface was cleaned in the dry box with a nonaqueous etchant consisting of 0.2% by volume Br2. in absolute ethanol, rinsed in ethanol, blown dry with nitrogen and loaded into the XPS chamber with no air exposure. The etchant forms reaction products (HgBr₂, BaBr₂, CaBr₂, CuBr₂) which are soluble in ethanol, and has yielded high quality surfaces for other HTS materials. The etch rate was determined to be -400-600 A/min. The XPS spectra are accumulated on a Surface Science Instruments SSX-501 spectrometer with monochromatized Al K_{α} x-rays (1 486.6 eV) and a base pressure of 5 x 10^{-10} Torr. The x-ray beam diameter is 150 μm for the core level measurements and 300 µm for the valence band measurements, and the pass energy of the electron energy analyzer is 25 eV, parameters which yield a peak full width at half maximum (FWHM) of 0.7 eV for the Au 4f7/2 signal from a gold film. The photoelectron emission is normal to the sample surface. After completion of the XPS measurements, ac susceptibility measurements show a superconducting transition onset near 116 K with a transition width of 7 K, verifying that the film remains superconducting after transport, etching, and vacuum exposure.

XPS spectra measured **prior** to etching exhibit dominant high binding energy signals which are affected by differential sample charging, as determined by varying the filament current on an electron flood gun. Low binding energy **spectral** features attributable to the superconducting phase are also detectable as minor components. No charging is observed after etching, indicating that insulating surface phases are removed by the **etchant**. Small signals from the **SrTiO3** substrate are observed even prior to etching, indicating that the film contains some voids, and increase in intensity with increasing etch time. Signals from the substrate could potentially affect measurements of the O 1s core level and the valence band (hybridized **Cu** 3d -0 2p states). This effect can be estimated from the **measuredSr** 3d and Ti 2p intensities and the photoelectric cross sections to be <10% of the total O 1s intensity and <2% of the valence band signal after 30s of etching, and approximately twice those levels after 60s, Accordingly, only spectra measured after 30s of etching are presented below, unless specified otherwise. **The** measured **stoichiometry** after etching is **Hg:Ba:Ca:Cu:O≈** 0.6:2:1:2:8. The **Hg** deficiency is likely due to the volatility of Hg, while the excess O is **related** to contaminant species, as discussed and shown in the spectra below.

The O 1s signal, which is most commonly used to assess surface. cleanliness, is shown in Fig. 1(a). The dominant peak near 528.5 eV is consistent with measurements from other HTS materials, and is thus assigned to the superconducting phase, and has a shoulder on the low binding energy side. The peak near S31.5 CV is dominant prior to etching and in previous measurements of Hg cuprates, and has been determined to originate from nonsuperconducting surface or grain boundary species in studies of other HTS materials. This was verified in this work with angle-resolved measurements, in which the high binding energy signal is enhanced at grazing photoelectron emission angles, The O1s signal measured from an etched T1-2212 film is shown in Fig. 1(b) to be very similar to the spectrum in Fig. 1(a). The components of the spectra can be resolved in the second derivatives, as shown in Figs. 1(c) and 1(d). These components have binding energies of 527.8 eV and 528.7 eV for Hg-1212, and are assigned to

study.⁹ In this work, the intensities of the higher binding energy components are enhanced for a grazing photoelectron emission angle and are dominant prior to etching, and are therefore assigned to nonsuperconducting species. The lower binding energy signals, which are dominant after etching and assigned to Hg-1212, are virtually identical to those observed forT1-2212.11*]8 These signals occur at significantly lower binding energies than those measured for Ba and Ca metals, an observation which is characteristic of the alkaline earth core levels for other HTS materials. ¹⁸ Two Ca 2p doublets have also been observed for T1-2212 and Bi₂Sr₂CaCu₂O₈₊₈, ¹¹, ¹⁸ and have been interpreted as originating from cation disorder and occupation of inequivalent lattice sites.

The Cu 2p_{3/2} signalofHg-1212, shown in Fig. 4, is typical of Cu⁺² compounds, with a high binding energy manifold corresponding to d⁹ final state screening and a more intense peak at 933 eV corresponding to well-screened d¹⁰ states resulting from ligand-to-metal charge transfer. This data is qualitatively similar to measurements in one earlier study,⁹ but differs from a study¹⁰ of Hg-1 201 scraped in vacuum, in which no signal corresponding to d⁹ screening was observed. Scrape-induced surface damage of other HI'S materials has previously been shown^{8,19} to result in loss of intensity in this spectral region due to reduction of Cu⁺² to Cu⁺¹. The same study¹⁰ also concluded that Cu occurred in +1, i-2, and +3 oxidation states based on the observed lineshape of the d¹⁰ signal. However, the shape of the d¹⁰ signal results from a multiplet of final states rather than multiple oxidation states, as discussed in detail elsewhere.²⁰ The Cu₂p_{3/2} signal in Fig. 4 is similar to measurements of other HTS cuprates,^{8,20} though the d⁹/d¹⁰ intensity ratio of 0.38 is slightly lower than the value of 0.45 observed for TI-2212. ¹¹ This difference may reflect differences in electron correlation in these similar materials.

Fig. 5 shows the Hg 5d and Ba 5p shallow core levels and the valence band of Hg-1 212, which consists of hybridized Cu 3d and O 2p states. This is the first published valence band spectrum for a Hg cuprate superconductor. For the photon energy used in this study, the Cu 3d character is dominant (87% of the spectral weight assuming ideal stoichiometry) due to a higher

photoelectric cross section. Shown below the valence band is the Cu 3d partial density of states from band structure calculations, ¹² shifted by 2.2 eV to approximately match the envelope of the measured density of states. Similar shifts have been found necessary for other HTS materials, and have been attributed to electron correlation effects which are inadequately treated in the calculations. The insets in Fig. 5 show the Fermi edge measured after 30s and 60s of etching, verifying the high quality of the data presented here.

The data presented above show that the core levels of Hg-1212 are similar to those of other HTS cuprates, and are nearly identical to those measured for T1-2212. However, despite the similarities observed in the Hg-12,12 and T1-2212 core levels and the chemical and structural similarities, distinct differences are observed in the valence bands, as shown in Fig. 6. The density of states at the Fermi level is lower for Hg-1212 despite having a higher T_c. The Hg-1212 valence band is also significantly broader on the high binding energy side. Although there are some differences in the Hg-1212 and T1-2212 Cu 3d partial densities of states, ^{12,13} they do not appear to be sufficient to account for the data in Fig. 6 near 6 eV binding energy. The most notable differences occur for the apical oxygen 2p partial densities of states, shown below the valence bands in Fig. 6, which are qualitatively consistent with the differences observed in the measured valence bands. Both of the calculated spectra have been shifted by the ~2 eV necessary to align the Cu 3d partial densities of states with the measured valence bands.

In summary, XPS has been used to characterize an epitaxial thin film of a mercury cuprate superconductor for the first time. Hg is found to be in a single chemical state, contrary to previous reports based on measurements from sintered polycrystalline pellets. The Ba, Ca, Cu, and O core levels are similar to those measured from other HTS cuprates, and are nearly identical to those of T1-2212, which is chemically and structurally most similar to Hg-1212. Two O 1s signals assigned to CU-O planes anti Hg-O bonds are distinguishable, as are two Ca 2p signals which may be due to cation disorder. These are the first XPS measurements of a Hg cuprate in which signals attributable to the superconducting phase dominate all the core level spectra. Despite the

similarities in the core level spectra, distinct differences are observed in the valence bands of **Hg-** 1212 and T1-2212 which are consistent with differences in the calculated apical oxygen densities of states. This work presents the first published valence band spectrum of a **Hg cuprate** superconductor, and the first observation of a clear Fermi edge.

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Figure Captions

- 1. The O 1s spectra measured from chemically-etched epitaxial thin films of (a) Hg-1212, and (b) Tl-2212 (from Ref. 14). The second derivative of the spectra in (a) and (b) are shown in (c) and (d), respectively.
- 2. The Hg 4f and Ba 4d core level signals measured from Hg- 1212.
- 3. The Ca 2p core level signal measured from Hg- 1212.
- 4. The Cu 2p_{3/2} core level signal measured from Hg-12 12.
- 5. The valence band and the Hg 5d and Ba 5p shallow core level signals measured from Hg-1212, Below the valence band is the calculated Cu 3d partial density of states from Ref.
 12. Insets show closeups of the Fermi edges observed after 30s and 60s of etching,
- Comparison of the valence bands of Hg-1212 (this work) and Tl-2212 (from Ref. 11).
 Below are the calculated apical oxygen partial densities of states of Hg-1212 (from Ref. 12) and Tl-2212 (from Ref. 13).











